Influence of extrinsic properties on magnetism and magnetotransport in Mn doped Bi₂Te₃ topological insulator with self-organized MnBi₂Te₄ layers.

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There is a growing interest in magnetic topological insulators (MTIs), which combine the properties of materials exhibiting magnetic order with properties of topological matter. The combination of these features leads to exotic quantum phenomena such as the quantum anomalous Hall effect (QAHE) and the axion insulator phase [1–5].

Among the MTIs one of the systems widely studied is the topological insulator bismuth telluride (Bi_2Te_3) doped with manganese (Mn). Under appropriate growth conditions, Mn ions can form self-organized heterostructures composed of an alternating sequence of MnBi_2Te_4 septuple layers (SLs) and *n*-fold Bi_2Te_3 quintuple layers (QLs). The MnBi_2Te_4/(Bi_2Te_3)_n compounds belong to the family of intrinsic MTIs which, compared to dilute MTIs with randomly distributed Mn atoms, can provide more uniform electronic and magnetic properties resulting in larger Dirac mass gap as well as an increase in the QAHE realization temperature [6–8]. The QAHE state has been indeed achieved in crystal flakes with the MnBi_2Te_4/(Bi_2Te_3)_n naturally occurring superlattice at record-high temperature [2]. It became simultaneously clear that the reduction of the influence of extrinsic effects, such as inherent magnetic disorder caused by different locations of Mn dopants and bulk carrier density, is necessary to master the QAHE. In my presentation, I will talk about our recent advances in understanding the role of both of these issues [9,10].

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